Description

The 9ZXL1930 is a low power version of the Intel DB1900Z Differential Buffer utilizing Low-Power HCSL (LP-HCSL) outputs to reduce power consumption more than 50% from the original IDT9ZX21901. It is suitable for PCI-Express Gen1/2/3 or QPI/UPI applications, and uses a fixed external feedback to maintain low drift for demanding QPI/UPI applications.

Recommended Application

Buffer for Romley, Grantley and Purley Servers

Key Specifications

- Cycle-to-cycle jitter: < 50ps
- Output-to-output skew: <85ps
- Input-to-output delay: Fixed at 0 ps
- Input-to-output delay variation: <50ps
- Phase jitter: PCIe Gen3 < 1ps rms
- Phase jitter: QPI/UPI 9.6GB/s < 0.2ps rms

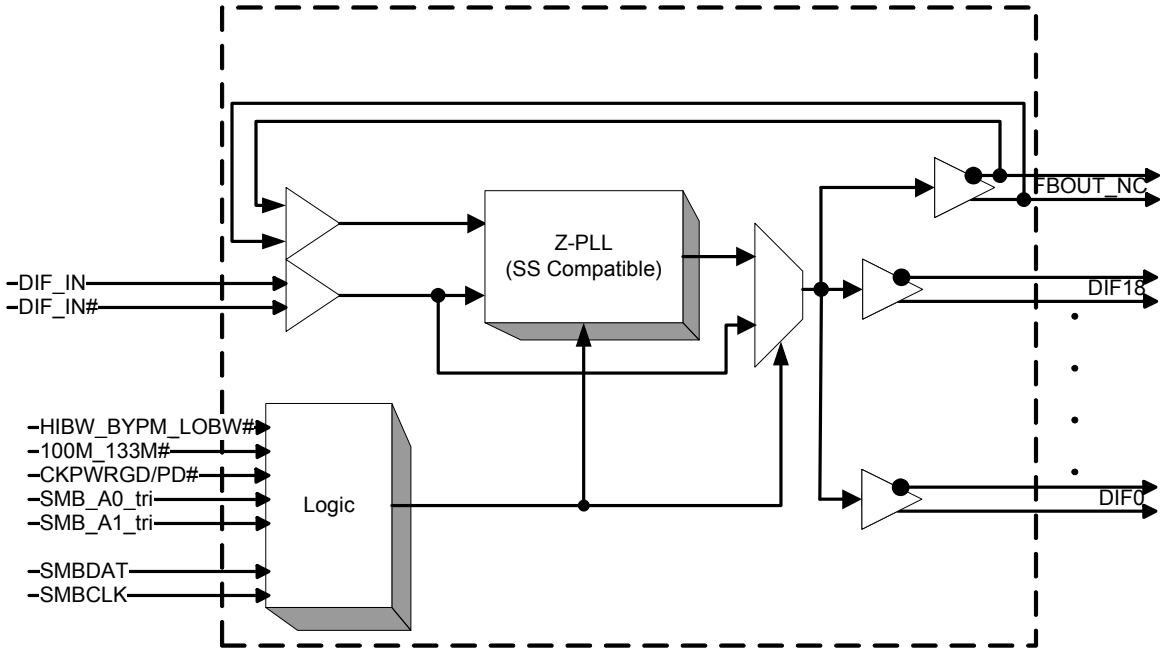
Features/Benefits

- Fixed feedback path; 0ps input-to-output delay
- 9 Selectable SMBus addresses; Multiple devices can share same SMBus segment
- Separate VDDIO for outputs; allows maximum power savings
- PLL or bypass mode; PLL can dejitter incoming clock
- Selectable PLL BW; minimizes jitter peaking in downstream PLL's
- Spread spectrum compatible; tracks spreading input clock for EMI reduction
- SMBus Interface; unused outputs can be disabled
- 100MHz & 133.33MHz PLL mode; Legacy QPI/UPI support
- Differential outputs are Low/Low in power down; Maximum power savings

Output Features

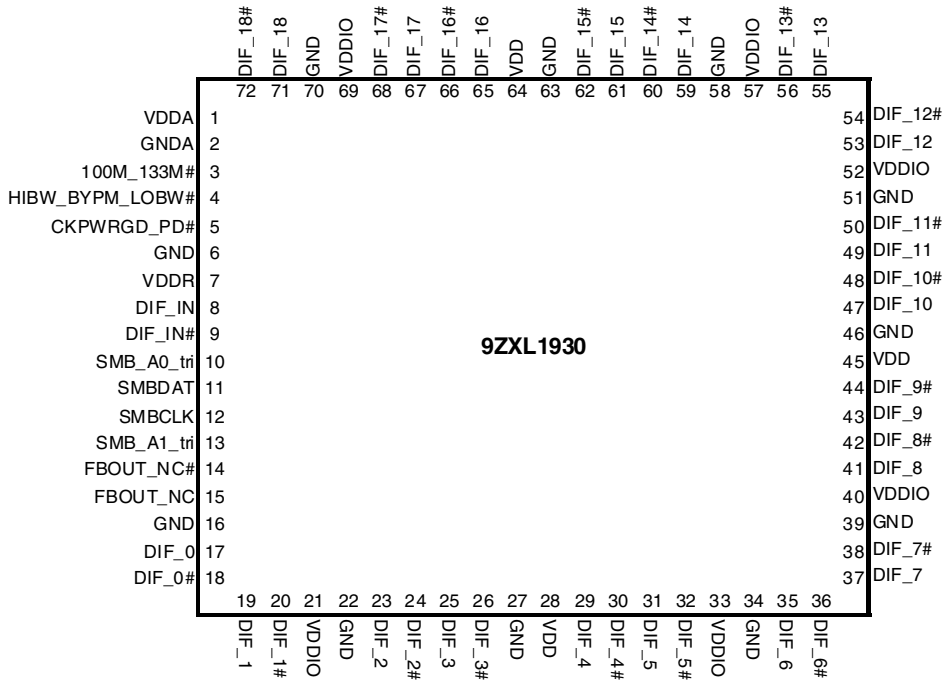
- 19 - LP-HCSL Differential Output Pairs

Block Diagram



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Pin Configuration



Power Management Table

Inputs		Control Bits	Outputs		PLL State
CKPWRGD_PD#	DIF_IN/ DIF_IN#	SMBus EN bit	DIF_x/ DIF_x#	FBOUT_NC/ FB_OUT_NC#	
0	X	X	Low/Low	Low/Low	OFF
1	Running	0	Low/Low	Running	ON
		1	Running	Running	ON

Power Connections

Pin Number			Description
VDD	VDDIO	GND	
1		2	Analog PLL
7		6	Analog Input
28, 45, 64	21, 33, 40, 52, 57, 69	16, 22, 27, 34, 39, 46, 51, 58, 63, 70	DIF clocks

Functionality at Power-up (PLL mode)

100M_133M#	DIF_IN (MHz)	DIFx (MHz)
1	100.00	DIF_IN
0	133.33	DIF_IN

PLL Operating Mode Table

HiBW_BypM_LoBW#	Byte0, bit (7:6)
Low (PLL Low BW)	00
Mid (Bypass)	01
High (PLL High BW)	11

NOTE: PLL is off in Bypass mode

Tri-Level Input Thresholds

Level	Voltage
Low	<0.8V
Mid	1.2<Vin<1.8V
High	Vin > 2.2V

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Pin Descriptions

PIN #	PIN NAME	PIN TYPE	DESCRIPTION
1	VDDA	PWR	3.3V power for the PLL core.
2	GNDA	PWR	Ground pin for the PLL core.
3	100M_133M#	IN	3.3V Input to select operating frequency See Functionality Table for Definition
4	HIBW_BYPM_LOBW#	IN	Trilevel input to select High BW, Bypass or Low BW mode. See PLL Operating Mode Table for Details.
5	CKPWRGD_PD#	IN	Notifies device to sample latched inputs and start up on first high assertion, or exit Power Down Mode on subsequent assertions. Low enters Power Down Mode.
6	GND	PWR	Ground pin.
7	VDDR	PWR	3.3V power for differential input clock (receiver). This VDD should be treated as an analog power rail and filtered appropriately.
8	DIF_IN	IN	0.7 V Differential TRUE input
9	DIF_IN#	IN	0.7 V Differential Complementary Input
10	SMB_A0_tri	IN	SMBus address bit. This is a tri-level input that works in conjunction with the SMB_A1 to decode 1 of 9 SMBus Addresses.
11	SMBDAT	I/O	Data pin of SMBUS circuitry, 5V tolerant
12	SMBCLK	IN	Clock pin of SMBUS circuitry, 5V tolerant
13	SMB_A1_tri	IN	SMBus address bit. This is a tri-level input that works in conjunction with the SMB_A0 to decode 1 of 9 SMBus Addresses.
14	FBOUT_NC#	OUT	Complementary half of differential feedback output. This pin should NOT be connected to anything outside the chip. It exists to provide delay path matching to get 0 propagation delay.
15	FBOUT_NC	OUT	True half of differential feedback output. This pin should NOT be connected to anything outside the chip. It exists to provide delay path matching to get 0 propagation delay.
16	GND	PWR	Ground pin.
17	DIF_0	OUT	0.7V differential true clock output
18	DIF_0#	OUT	0.7V differential Complementary clock output
19	DIF_1	OUT	0.7V differential true clock output
20	DIF_1#	OUT	0.7V differential Complementary clock output
21	VDDIO	PWR	Power supply for differential outputs
22	GND	PWR	Ground pin.
23	DIF_2	OUT	0.7V differential true clock output
24	DIF_2#	OUT	0.7V differential Complementary clock output
25	DIF_3	OUT	0.7V differential true clock output
26	DIF_3#	OUT	0.7V differential Complementary clock output
27	GND	PWR	Ground pin.
28	VDD	PWR	Power supply, nominal 3.3V
29	DIF_4	OUT	0.7V differential true clock output
30	DIF_4#	OUT	0.7V differential Complementary clock output
31	DIF_5	OUT	0.7V differential true clock output
32	DIF_5#	OUT	0.7V differential Complementary clock output
33	VDDIO	PWR	Power supply for differential outputs
34	GND	PWR	Ground pin.
35	DIF_6	OUT	0.7V differential true clock output
36	DIF_6#	OUT	0.7V differential Complementary clock output

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Pin Descriptions (cont.)

PIN #	PIN NAME	PIN TYPE	DESCRIPTION
37	DIF_7	OUT	0.7V differential true clock output
38	DIF_7#	OUT	0.7V differential Complementary clock output
39	GND	PWR	Ground pin.
40	VDDIO	PWR	Power supply for differential outputs
41	DIF_8	OUT	0.7V differential true clock output
42	DIF_8#	OUT	0.7V differential Complementary clock output
43	DIF_9	OUT	0.7V differential true clock output
44	DIF_9#	OUT	0.7V differential Complementary clock output
45	VDD	PWR	Power supply, nominal 3.3V
46	GND	PWR	Ground pin.
47	DIF_10	OUT	0.7V differential true clock output
48	DIF_10#	OUT	0.7V differential Complementary clock output
49	DIF_11	OUT	0.7V differential true clock output
50	DIF_11#	OUT	0.7V differential Complementary clock output
51	GND	PWR	Ground pin.
52	VDDIO	PWR	Power supply for differential outputs
53	DIF_12	OUT	0.7V differential true clock output
54	DIF_12#	OUT	0.7V differential Complementary clock output
55	DIF_13	OUT	0.7V differential true clock output
56	DIF_13#	OUT	0.7V differential Complementary clock output
57	VDDIO	PWR	Power supply for differential outputs
58	GND	PWR	Ground pin.
59	DIF_14	OUT	0.7V differential true clock output
60	DIF_14#	OUT	0.7V differential Complementary clock output
61	DIF_15	OUT	0.7V differential true clock output
62	DIF_15#	OUT	0.7V differential Complementary clock output
63	GND	PWR	Ground pin.
64	VDD	PWR	Power supply, nominal 3.3V
65	DIF_16	OUT	0.7V differential true clock output
66	DIF_16#	OUT	0.7V differential Complementary clock output
67	DIF_17	OUT	0.7V differential true clock output
68	DIF_17#	OUT	0.7V differential Complementary clock output
69	VDDIO	PWR	Power supply for differential outputs
70	GND	PWR	Ground pin.
71	DIF_18	OUT	0.7V differential true clock output
72	DIF_18#	OUT	0.7V differential Complementary clock output

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Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the 9ZXL1930. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
3.3V Core Supply Voltage	VDDA, R				4.6	V	1,2
3.3V Logic Supply Voltage	VDD				4.6	V	1,2
I/O Supply Voltage	VDDIO				4.6	V	1,2
Input Low Voltage	V_{IL}		GND-0.5			V	1
Input High Voltage	V_{IH}	Except for SMBus interface			V_{DD}+0.5V	V	1
Input High Voltage	V_{IHSMB}	SMBus clock and data pins			5.5V	V	1
Storage Temperature	Ts		-65		150	°C	1
Junction Temperature	Tj				125	°C	1
Input ESD protection	ESD prot	Human Body Model	2000			V	1

[1]Guaranteed by design and characterization, not 100% tested in production.

[2] Operation under these conditions is neither implied nor guaranteed.

Electrical Characteristics–DIF_IN Clock Input Parameters

TA = T_{COM}; Supply Voltage VDD/VDDA = 3.3 V +/-5%, VDDIO = 1.05 to 3.3V +/-5%. See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Input Crossover Voltage - DIF_IN	V_{CROSS}	Cross Over Voltage	150		900	mV	1
Input Swing - DIF_IN	V_{SWING}	Differential value	300			mV	1
Input Slew Rate - DIF_IN	dv/dt	Measured differentially	0.4		8	V/ns	1,2
Input Leakage Current	I_{IN}	$V_{IN} = V_{DD}$, V_{IN} = GND	-5		5	uA	
Input Duty Cycle	d_{tin}	Measurement from differential wavefrom	45		55	%	1
Input Jitter - Cycle to Cycle	J_{DIFIn}	Differential Measurement	0		125	ps	1

[1] Guaranteed by design and characterization, not 100% tested in production.

[2]Slew rate measured through +/-75mV window centered around differential zero

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Electrical Characteristics–Input/Supply/Common Output Parameters

TA = T_{COM}; Supply Voltage VDD/VDDA = 3.3 V +/-5%, VDDIO = 1.05 to 3.3V +/-5%. See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Ambient Operating Temperature	T_{COM}	Commmercial range	0		70	°C	1
Input High Voltage	V_{IH}	Single-ended inputs, except SMBus, low threshold and tri-level inputs	2		V_{DD} + 0.3	V	1
Input Low Voltage	V_{IL}	Single-ended inputs, except SMBus, low threshold and tri-level inputs	GND - 0.3		0.8	V	1
Input Current	I_{IN}	Single-ended inputs, V_{IN} = GND, V_{IN} = VDD	-5		5	uA	1
	I_{INP}	Single-ended inputs V_{IN} = 0 V; Inputs with internal pull-up resistors V_{IN} = VDD; Inputs with internal pull-down resistors	-200		200	uA	1
Input Frequency	F_{ibyp}	V_{DD} = 3.3 V, Bypass mode	33		150	MHz	2
	F_{ipll}	V_{DD} = 3.3 V, 100MHz PLL mode	90	100.00	110	MHz	2
	F_{ipll}	V_{DD} = 3.3 V, 133.33MHz PLL mode	120	133.33	147	MHz	2
Pin Inductance	L_{pin}				7	nH	1
Capacitance	C_{IN}	Logic Inputs, except DIF_IN	1.5		5	pF	1
	C_{INDIF_IN}	DIF_IN differential clock inputs	1.5		2.7	pF	1,4
	C_{OUT}	Output pin capacitance			6	pF	1
Clk Stabilization	T_{STAB}	From V_{DD} Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock			1	ms	1,2
Input SS Modulation Frequency	f_{MODIN}	Allowable Frequency (Triangular Modulation)	30		33	kHz	1
OE# Latency	$t_{LATOE\#}$	DIF start after OE# assertion DIF stop after OE# deassertion	4		12	clocks	1
Tdrive_PD#	t_{DRVPD}	DIF output enable after PD# de-assertion			300	us	1,3
Tfall	t_F	Fall time of control inputs			5	ns	1,2
Trise	t_R	Rise time of control inputs			5	ns	1,2
SMBus Input Low Voltage	V_{ILSMB}				0.8	V	1
SMBus Input High Voltage	V_{IHSMB}		2.1		V_{DDSMB}	V	1
SMBus Output Low Voltage	V_{OLSMB}	@ I_{PULLUP}			0.4	V	1
SMBus Sink Current	I_{PULLUP}	@ V_{OL}	4			mA	1
Nominal Bus Voltage	V_{DDSMB}	3V to 5V +/- 10%	2.7		5.5	V	1
SCLK/SDATA Rise Time	t_{RSMB}	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t_{FSMB}	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating Frequency	f_{MAXSMB}	Maximum SMBus operating frequency			100	kHz	1,5

[1]Guaranteed by design and characterization, not 100% tested in production.

[2]Control input must be monotonic from 20% to 80% of input swing.

[3]Time from deassertion until outputs are >200 mV

[4]DIF_IN input

[5]The differential input clock must be running for the SMBus to be active

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Electrical Characteristics–DIF Low-Power HCSL Differential Outputs

TA = T_{COM}; Supply Voltage VDD/VDDA = 3.3 V +/-5%, VDDIO = 1.05 to 3.3V +/-5%. See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew rate	Trf	Scope averaging on	1	3	4	V/ns	1, 2, 3
Slew rate matching	ΔTrf	Slew rate matching, Scope averaging on		7.6	20	%	1, 2, 4
Voltage High	VHigh	Statistical measurement on single-ended signal using oscilloscope math function. (Scope averaging on)	660	757	850	mV	1
Voltage Low	VLow		-150	16	150		1
Max Voltage	Vmax	Measurement on single ended signal using absolute value. (Scope averaging off)		857	1150	mV	1
Min Voltage	Vmin		-300	-36			1
Vswing	Vswing	Scope averaging off	300			mV	1, 2
Crossing Voltage (abs)	Vcross_abs	Scope averaging off	300	469	550	mV	1, 5
Crossing Voltage (var)	Δ-Vcross	Scope averaging off		14	140	mV	1, 6

[1]Guaranteed by design and characterization, not 100% tested in production. C_L = 2pF with R_S = 33Ω for Zo = 50Ω (100Ω differential trace impedance).

[2] Measured from differential waveform

[3] Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

[4] Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

[5] Vcross is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

[6] The total variation of all Vcross measurements in any particular system. Note that this is a subset of Vcross_min/max (Vcross absolute) allowed. The intent is to limit Vcross induced modulation by setting Δ-Vcross to be smaller than Vcross absolute.

Electrical Characteristics–Current Consumption

TA = T_{COM}; Supply Voltage VDD/VDDA = 3.3 V +/-5%, VDDIO = 1.05 to 3.3V +/-5%. See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Operating Supply Current	I_{DDVDD}	All outputs @100MHz, C_L = 2pF; Zo=85 Ω		23	35	mA	1
	$I_{DDVDDA/R}$	All outputs @100MHz, C_L = 2pF; Zo=85 Ω		12	20	mA	1
	$I_{DDVDDIO}$	All outputs @100MHz, C_L = 2pF; Zo=85 Ω		151	175	mA	1
Powerdown Current	$I_{DDVDDPD}$	All differential pairs low/low		2.9	6	mA	1,2
	$I_{DDVDDA/RPD}$	All differential pairs low/low		4.4	6	mA	1,2
	$I_{DDVDDIOPD}$	All differential pairs low/low		0.05	1.5	mA	1,2

[1] Guaranteed by design and characterization, not 100% tested in production.

[2] With input clock running. Stopping the input clock will result in lower numbers.

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Electrical Characteristics–Skew and Differential Jitter Parameters

TA = T_{COM}; Supply Voltage VDD/VDDA = 3.3 V +/-5%, VDDIO = 1.05 to 3.3V +/-5%. See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
CLK_IN, DIF[x:0]	t_{SPO_PLL}	Input-to-Output Skew in PLL mode nominal value @ 25°C, 3.3V	-100	-44	100	ps	1,2,4,5,8
CLK_IN, DIF[x:0]	t_{PD_BYP}	Input-to-Output Skew in Bypass mode nominal value @ 25°C, 3.3V	2.5	3.6	4.5	ns	1,2,3,5,8
CLK_IN, DIF[x:0]	t_{DSPO_PLL}	Input-to-Output Skew Varation in PLL mode across voltage and temperature	-50	-2	50	ps	1,2,3,5,8
CLK_IN, DIF[x:0]	t_{DSPO_BYP}	Input-to-Output Skew Varation in Bypass mode across voltage and temperature	-250		250	ps	1,2,3,5,8
CLK_IN, DIF[x:0]	t_{DTE}	Random Differential Tracking error beween two 9ZX devices in Hi BW Mode		3	5	ps (rms)	1,2,3,5,8
CLK_IN, DIF[x:0]	t_{DSSTE}	Random Differential Spread Spectrum Tracking error beween two 9ZX devices in Hi BW Mode		15	75	ps	1,2,3,5,8
DIF{x:0]	t_{SKEW_ALL}	Output-to-Output Skew across all outputs (Common to Bypass and PLL mode)		76	85	ps	1,2,3,8
PLL Jitter Peaking	$j_{peak\text{-}hibw}$	LOBW#_BYPASS_HIBW = 1	0	1.75	2.5	dB	7,8
PLL Jitter Peaking	$j_{peak\text{-}lobw}$	LOBW#_BYPASS_HIBW = 0	0	0.75	2	dB	7,8
PLL Bandwidth	pll_{HIBW}	LOBW#_BYPASS_HIBW = 1	2	3.33	4	MHz	8,9
PLL Bandwidth	pll_{LOBW}	LOBW#_BYPASS_HIBW = 0	0.7	1.18	1.4	MHz	8,9
Duty Cycle	t_{DC}	Measured differentially, PLL Mode	45	50.4	55	%	1
Duty Cycle Distortion	t_{DCD}	Measured differentially, Bypass Mode @100MHz	-2	0	2	%	1,10
Jitter, Cycle to cycle	$t_{jcyc\text{-}cyc}$	PLL mode		24	50	ps	1,11
		Additive Jitter in Bypass Mode		0	50	ps	1,11

Notes for preceding table:

[1] Measured into fixed 2 pF load cap. Input to output skew is measured at the first output edge following the corresponding input.

[2] Measured from differential cross-point to differential cross-point. This parameter can be tuned with external feedback path, if present.

[3] All Bypass Mode Input-to-Output specs refer to the timing between an input edge and the specific output edge created by it.

[4] This parameter is deterministic for a given device

[5] Measured with scope averaging on to find mean value.

[6.] t is the period of the input clock

[7] Measured as maximum pass band gain. At frequencies within the loop BW, highest point of magnification is called PLL jitter peaking.

[8.] Guaranteed by design and characterization, not 100% tested in production.

[9] Measured at 3 db down or half power point.

[10] Duty cycle distortion is the difference in duty cycle between the output and the input clock when the device is operated in bypass mode.

[11] Measured from differential waveform

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Electrical Characteristics–Phase Jitter Parameters

TA = T_{COM}; Supply Voltage VDD/VDDA = 3.3 V +/-5%, VDDIO = 1.05 to 3.3V +/-5%. See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	Notes
Phase Jitter, PLL Mode	$t_{jphPCIeG1}$	PCIe Gen 1		30	86	ps (p-p)	1,2,3
	$t_{jphPCIeG2}$	PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		1.0	3	ps (rms)	1,2
		PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		1.7	3.1	ps (rms)	1,2
	$t_{jphPCIeG3}$	PCIe Gen 3 (PLL BW of 2-4MHz, CDR = 10MHz)		0.38	1	ps (rms)	1,2,4
	t_{jphQPI_SMI}	QPI & SMI (100MHz or 133MHz, 4.8Gb/s, 6.4Gb/s 12UI)		0.18	0.5	ps (rms)	1,5
		QPI & SMI (100MHz, 8.0Gb/s, 12UI)		0.13	0.3	ps (rms)	1,5
		QPI & SMI (100MHz, 9.6Gb/s, 12UI)		0.10	0.2	ps (rms)	1,5
Additive Phase Jitter, Bypass mode	$t_{jphPCIeG1}$	PCIe Gen 1		0	10	ps (p-p)	1,2,3
	$t_{jphPCIeG2}$	PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		0.0	0.3	ps (rms)	1,2,6
		PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		0.0	0.7	ps (rms)	1,2,6
	$t_{jphPCIeG3}$	PCIe Gen 3 (PLL BW of 2-4MHz, CDR = 10MHz)		0.0	0.3	ps (rms)	1,2,4,6
	t_{jphQPI_SMI}	QPI & SMI (100MHz or 133MHz, 4.8Gb/s, 6.4Gb/s 12UI)		0.12	0.3	ps (rms)	1,5,6
		QPI & SMI (100MHz, 8.0Gb/s, 12UI)		0.00	0.1	ps (rms)	1,5,6
		QPI & SMI (100MHz, 9.6Gb/s, 12UI)		0.00	0.1	ps (rms)	1,5,6

[1] Applies to all outputs.

[2] See http://www.pcisig.com for complete specs

[3] Sample size of at least 100K cycles. This figures extrapolates to 108ps pk-pk @ 1M cycles for a BER of 1-12.

[4] Subject to final ratification by PCI SIG.

[5] Calculated from Intel-supplied Clock Jitter Tool v 1.6.3

[6] For RMS figures, additive jitter is calculated by solving the following equation: (Additive jitter)^2 = (total jittter)^2 - (input jitter)^2

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Clock Periods–Differential Outputs with Spread Spectrum Disabled

SSC OFF	Center Freq. MHz	Measurement Window							Units	Notes
		1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
		-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max		
DIF	100.00	9.94900		9.99900	10.00000	10.00100		10.05100	ns	1,2,3
	133.33	7.44925		7.49925	7.50000	7.50075		7.55075	ns	1,2,4

Clock Periods–Differential Outputs with Spread Spectrum Enabled

SSC ON	Center Freq. MHz	Measurement Window							Units	Notes
		1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
		-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max		
DIF	99.75	9.94906	9.99906	10.02406	10.02506	10.02607	10.05107	10.10107	ns	1,2,3
	133.00	7.44930	7.49930	7.51805	7.51880	7.51955	7.53830	7.58830	ns	1,2,4

Notes:

[1] Guaranteed by design and characterization, not 100% tested in production.

[2] All Long Term Accuracy specifications are guaranteed with the assumption that the input clock complies with CK420BQ/CK410B+ accuracy requirements (+/-100ppm). The 9ZXL1930 itself does not contribute to ppm error.

[3] Driven by SRC output of main clock, 100 MHz PLL Mode or Bypass mode

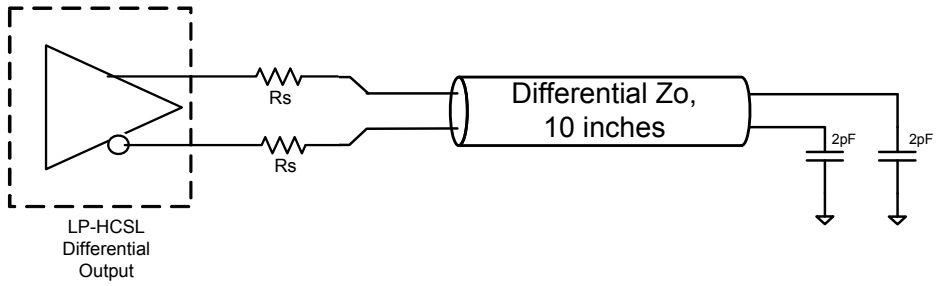
[4] Driven by CPU output of main clock, 133 MHz PLL Mode or Bypass mode

Test Loads

Differential Output Terminations

DIF Zo (Ω)	Rs (Ω)
100	33
85	27

9ZXL Differential Test Loads



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General SMBus Serial Interface Information

How to Write

- Controller (host) sends a start bit
- Controller (host) sends the write address
- IDT clock will **acknowledge**
- Controller (host) sends the beginning byte location = N
- IDT clock will **acknowledge**
- Controller (host) sends the byte count = X
- IDT clock will **acknowledge**
- Controller (host) starts sending Byte **N through Byte N+X-1**
- IDT clock will **acknowledg**e each byte **one at a time**
- Controller (host) sends a Stop bit

Index Block Write Operation			
Controller (Host)			**IDT (Slave/Receiver)**
T	starT bit		
Slave Address			
WR	WRite		
			ACK
Beginning Byte = N			
			ACK
Data Byte Count = X			
			ACK
Beginning Byte N		X Byte	
			ACK
O			
O			O
O			O
			O
Byte N + X - 1			
			ACK
P	stoP bit		

How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- IDT clock will **acknowledge**
- Controller (host) sends the beginning byte location = N
- IDT clock will **acknowledge**
- Controller (host) will send a separate start bit
- Controller (host) sends the read address
- IDT clock will **acknowledge**
- IDT clock will send the data byte count = X
- IDT clock sends Byte **N+X-1**
- IDT clock sends **Byte 0 through Byte X (if $X_{(H)}$ was written to Byte 8)**
- Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

Index Block Read Operation			
Controller (Host)			**IDT (Slave/Receiver)**
T	starT bit		
Slave Address			
WR	WRite		
			ACK
Beginning Byte = N			
			ACK
RT	Repeat starT		
Slave Address			
RD	ReaD		
			ACK
			Data Byte Count=X
ACK			
		X Byte	Beginning Byte N
ACK			
			O
O			O
O			O
O			
			Byte N + X - 1
N	Not acknowledge		
P	stoP bit		

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9ZXL1930 SMBus Addressing

SMB_A(1:0)_tri	SMBus Address (Rd/Wrt bit = 0)
00	D8
0M	DA
01	DE
M0	C2
MM	C4
M1	C6
10	CA
1M	CC
11	CE

SMBusTable: PLL Mode, and Frequency Select Register

Byte 0	Pin #	Name	Control Function	Type	0	1	Default
Bit 7	4	PLL Mode 1	PLL Operating Mode Rd back 1	R	See PLL Operating Mode		Latch
Bit 6	4	PLL Mode 0	PLL Operating Mode Rd back 0	R	Readback Table		Latch
Bit 5	72/71	DIF_18_En	Output Control overrides OE# pin	RW	Low/Low	Enable	1
Bit 4	68/67	DIF_17_En	Output Control overrides OE# pin	RW	Low/Low	Enable	1
Bit 3	66/65	DIF_16_En	Output Control overrides OE# pin	RW	Low/Low	Enable	1
Bit 2		Reserved					0
Bit 1		Reserved					0
Bit 0	3	100M_133M#	Frequency Select Readback	R	133MHz	100MHz	Latch

SMBusTable: Output Control Register

Byte 1	Pin #	Name	Control Function	Type	0	1	Default
Bit 7	38/37	DIF_7_En	Output Control overrides OE# pin	RW	Low/Low	Enable	1
Bit 6	35/36	DIF_6_En	Output Control overrides OE# pin	RW			1
Bit 5	31/32	DIF_5_En	Output Control overrides OE# pin	RW			1
Bit 4	29/30	DIF_4_En	Output Control overrides OE# pin	RW			1
Bit 3	25/26	DIF_3_En	Output Control overrides OE# pin	RW			1
Bit 2	23/24	DIF_2_En	Output Control overrides OE# pin	RW			1
Bit 1	19/20	DIF_1_En	Output Control overrides OE# pin	RW			1
Bit 0	17/18	DIF_0_En	Output Control overrides OE# pin	RW			1

SMBusTable: Output Control Register

Byte 2	Pin #	Name	Control Function	Type	0	1	Default
Bit 7	62/61	DIF_15_En	Output Control overrides OE# pin	RW	Low/Low	Enable	1
Bit 6	60/59	DIF_14_En	Output Control overrides OE# pin	RW			1
Bit 5	56/55	DIF_13_En	Output Control overrides OE# pin	RW			1
Bit 4	54/53	DIF_12_En	Output Control overrides OE# pin	RW			1
Bit 3	50/49	DIF_11_En	Output Control overrides OE# pin	RW			1
Bit 2	48/47	DIF_10_En	Output Control overrides OE# pin	RW			1
Bit 1	44/43	DIF_9_En	Output Control overrides OE# pin	RW			1
Bit 0	42/41	DIF_8_En	Output Control overrides OE# pin	RW			1

SMBusTable: Reserved Register

Byte 3	Pin #	Name	Control Function	Type	0	1	Default
Bit 7		Reserved					0
Bit 6		Reserved					0
Bit 5		Reserved					0
Bit 4		Reserved					0
Bit 3		Reserved					0
Bit 2		Reserved					0
Bit 1		Reserved					0
Bit 0		Reserved					0

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SMBusTable: Reserved Register

Byte 4	Pin #	Name	Control Function	Type	0	1	Default
Bit 7		Reserved					0
Bit 6		Reserved					0
Bit 5		Reserved					0
Bit 4		Reserved					0
Bit 3		Reserved					0
Bit 2		Reserved					0
Bit 1		Reserved					0
Bit 0		Reserved					0

SMBusTable: Vendor & Revision ID Register

Byte 5	Pin #	Name	Control Function	Type	0	1	Default
Bit 7	-	RID3	REVISION ID	R	A rev = 0000 B rev = 0001 etc.		X
Bit 6	-	RID2		R			X
Bit 5	-	RID1		R			X
Bit 4	-	RID0		R			X
Bit 3	-	VID3	VENDOR ID	R	-	-	0
Bit 2	-	VID2		R	-	-	0
Bit 1	-	VID1		R	-	-	0
Bit 0	-	VID0		R	-	-	1

SMBusTable: DEVICE ID

Byte 6	Pin #	Name	Control Function	Type	0	1	Default
Bit 7	-	Device ID 7 (MSB)		R	1930 is 193 Decimal or C1 Hex		1
Bit 6	-	Device ID 6		R			X
Bit 5	-	Device ID 5		R			X
Bit 4	-	Device ID 4		R			X
Bit 3	-	Device ID 3		R			X
Bit 2	-	Device ID 2		R			0
Bit 1	-	Device ID 1		R			0
Bit 0	-	Device ID 0		R			1

SMBusTable: Byte Count Register

Byte 7	Pin #	Name	Control Function	Type	0	1	Default
Bit 7		Reserved					0
Bit 6		Reserved					0
Bit 5		Reserved					0
Bit 4	-	BC4	Writing to this register configures how many bytes will be read back.	RW	Default value is 8 hex, so 9 bytes (0 to 8) will be read back by default.		0
Bit 3	-	BC3		RW			1
Bit 2	-	BC2		RW			0
Bit 1	-	BC1		RW			0
Bit 0	-	BC0		RW			0

SMBusTable: Reserved Register

Byte 8	Pin #	Name	Control Function	Type	0	1	Default
Bit 7		Reserved					0
Bit 6		Reserved					0
Bit 5		Reserved					0
Bit 4		Reserved					0
Bit 3		Reserved					0
Bit 2		Reserved					0
Bit 1		Reserved					0
Bit 0		Reserved					0

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DIF Reference Clock			
Common Recommendations for Differential Routing	Dimension or Value	Unit	Figure
L1 length, route as non-coupled 50ohm trace	0.5 max	inch	1
L2 length, route as non-coupled 50ohm trace	0.2 max	inch	1
L3 length, route as non-coupled 50ohm trace	0.2 max	inch	1
Rs (100 ohm differential traces)	33	ohm	1
Rs (85 ohm differential traces)	27	ohm	1

Down Device Differential Routing			
L4 length, route as coupled microstrip 100ohm differential trace	2 min to 16 max	inch	1
L4 length, route as coupled stripline 100ohm differential trace	1.8 min to 14.4 max	inch	1

Differential Routing to PCI Express Connector			
L4 length, route as coupled microstrip 100ohm differential trace	0.25 to 14 max	inch	2
L4 length, route as coupled stripline 100ohm differential trace	0.225 min to 12.6 max	inch	2

Figure 1: Down Device Routing

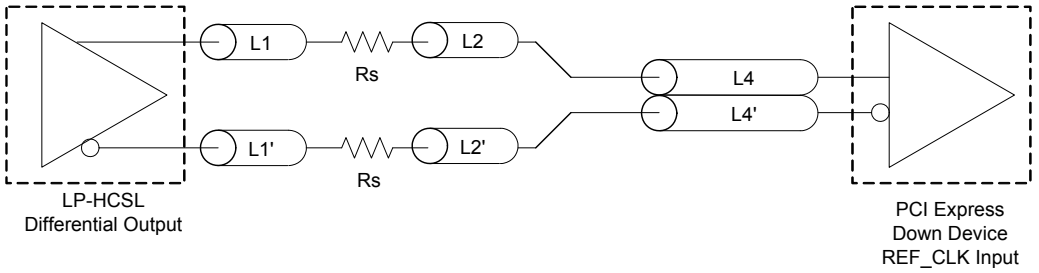
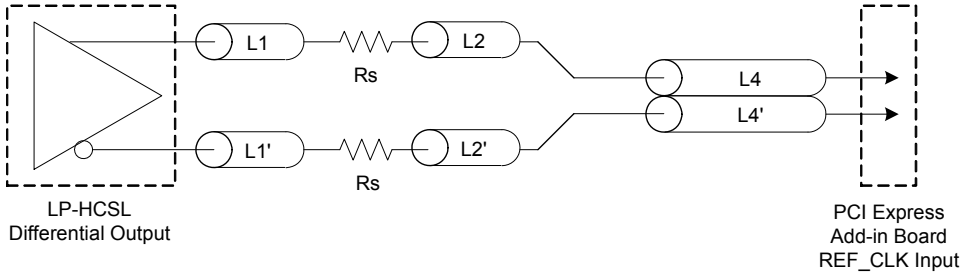


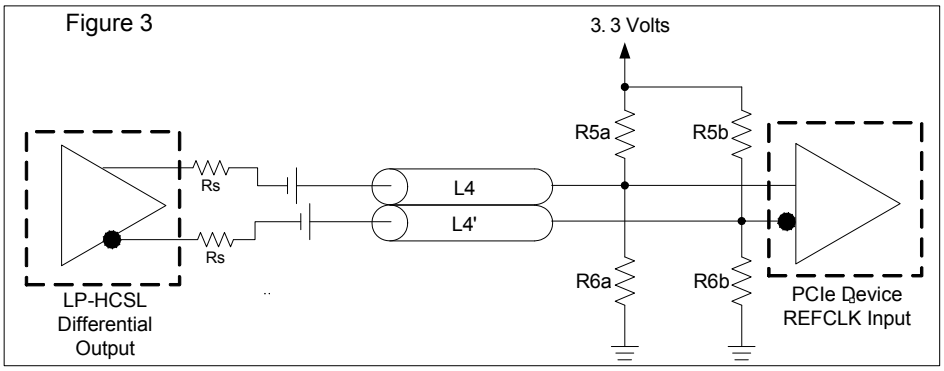
Figure 2: PCI Express Connector Routing



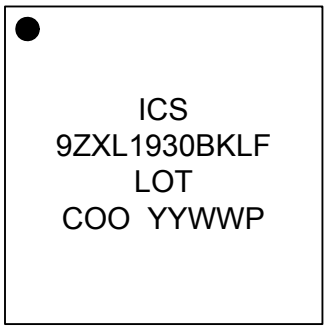
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Cable Connected AC Coupled Application (Figure 3)		
Component	Value	Note
R5a, R5b	8.2K 5%	
R6a, R6b	1K 5%	
Cc	0.1 µF	
Vcm	0.350 volts	

Figure 3



Marking Diagram

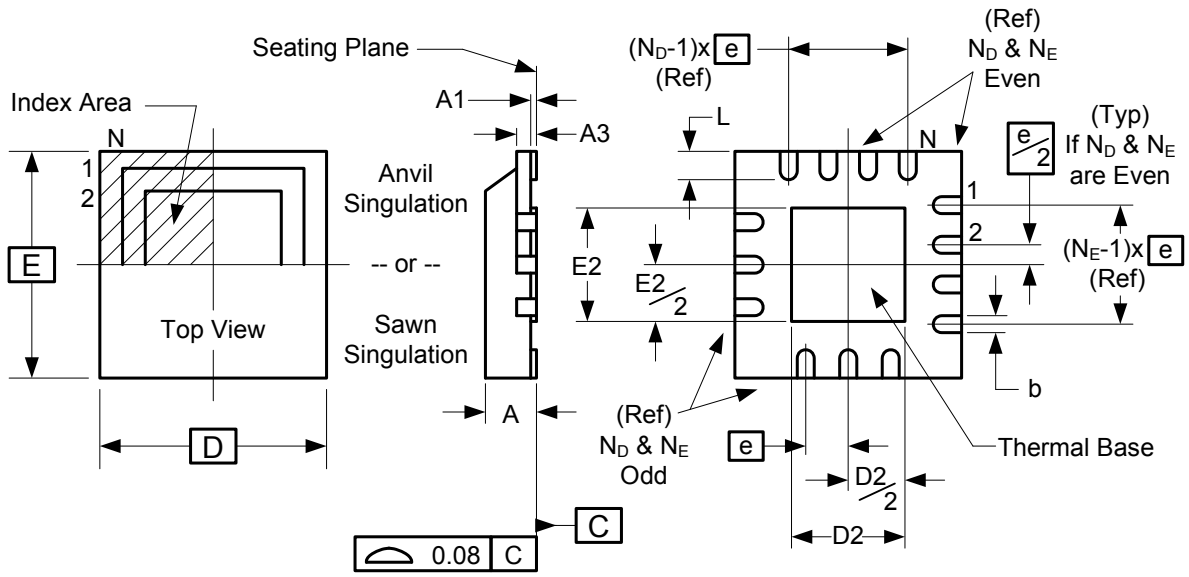


Notes:

1. 'LOT' is the lot number.
2. YYWW is the last two digits of the year and week that the part was assembled.
3. "LF" denotes RoHS compliant package.
4. 'COO" deontes country of origin.

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Package Outline and Package Dimensions (72-pin MLF)



	Millimeters	
Symbol	**Min**	**Max**
A	0.8	1.0
A1	0	0.05
A3	0.25 Reference	
b	0.18	0.3
e	0.50 BASIC	
D x E BASIC	10.00 x 10.00	
D2 MIN./MAX.	5.75	6.15
E2 MIN./MAX.	5.75	6.15
L MIN./MAX.	0.3	0.5
N_D	18	
N_E	18	

Ordering Information

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
9ZXL1930BKLF	see page 15	Tray	72-pin MLF	0 to +70° C
9ZXL1930BKLFT		Tape and Reel	72-pin MLF	0 to +70° C

"LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

“B” is the device revision designator (will not correlate with the datasheet revision).

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Revision History

Rev.	Issuer	Issue Date	Description	Page #
A	RDW	12/8/2011	1. Updated key specifications table Output to Output skew to 85ps 2. Updated Electrical Tables with typical specs 3. Updated Byte 5 for REV ID 4. Moved to Final	1,6-9,13
B	RDW	3/12/2012	1.Various typo fixes, changed output references to LP-HCSL. 2. Added Test Loads figure and table.	1,9,10,14
C	RDW	6/25/2214	1.Slightly increased MAX power down currents. 2. Clarified block diagram to indicate that there are multiple outputs. 3. Changed title of output characterisitics table to "Electrical Characteristics - DIF Low-Power HCSL Differential Outputs" to follow new standard. 4. Reformatted Figures 2 and 3 for consistency/clarity	1,7,14,15
D	RDW	11/20/2015	1. Updated QPI references to QPI/UPI 2. Updated DIF_IN table to match PCI SIG specification, no silicon change	1,5

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